Preliminary

275V 40-Channel Row Driver with SCR Outputs

Ordering Information

	Package Options				
Device	80-Lead Ceramic Gullwing	64-Lead 3-Sided Plastic Gullwing	Die		
HV506	HV506DG	HV506PG	HV506X		

Features

- Processed with HVDI[®] technology
- Symmetric row drive
- Output voltage up to 275V
- □ Source/Sink current 300mA (min.)
- Shift Register Speed 3MHz
- □ Pin-programmable shift direction (DIR)
- □ Hi-Rel processing available

Absolute Maximum Ratings

Logic supply voltage, LV _{DD} ¹		-0.5V to +15V
Output supply voltage, V _{DD} ¹		-0.5V to +15V
Substrate bias voltage, V_{sub}		See Note 3
Output voltage, HV _{OUT}		±300V
Logic input levels	-0	.5V to V _{DD} +0.5V
Continuous total power dissipation ²	Ceramic Plastic	1900mW 1200mW
Operating temperature range	Plastic Ceramic	-40°C to +85°C -55°C to +125°C
Storage temperature range		-65°C to +150°C
Lead temperature 1.6mm (1/16 inch) from case for 10 seconds)	260°C

Notes:

1. All voltages are referenced to $\rm V_{_{\rm SS}}.$

 For operation above 25°C ambient derate linearly to maximum operating temperture at 20mW/°C for plasitc and at 19mW/°C for ceramic.

3. V_{sub} must be the most positive with respect to V_{ss}.

12/13/01

General Description

The HV506 is a low-voltage serial to high-voltage parallel converter with push-pull outputs. It is especially suitable for use as a symmetric row driver in AC thin-film electroluminescent (ACTFEL) displays.

When the data reset pin (DR_{10}) is at logic high, it will reset all the outputs of the internal shift register to zero. At the same time, the output of the shift register will start shifting a logic high from the least significant bit to the most significant bit. The DR_{10} can be triggered at any time. The DIR pin controls the direction of data through the device. When DIR is at logic high, DR_{IDA} is the input and DR_{IOB} is the output. When DIR is grounded, DR_{IOB} is the input and the DR_{IOA} is the output. See the Output Sequence Operation Table for output sequence. The \overline{POL} and \overline{OE} pins perform the polarity select and output enable function respectively. Data is clocked through the shift register loaded on the low to high transition of the clock. A logic high in the shift register will cause the other corresponding output to swing to V_{DD} if \overline{POL} is high, or to V_{ss} if POL is low. All other outputs will be in the High-Z state. If OE is at logic high all outputs will be in the High-Z state. An output in the High-Z state may block up to 275V above V_{ss} or 275V below V_{DD} . The D_P/D_N pins are for the positive/negative discharge of the high voltage output HV_{out}. Data output buffers are provided for cascading devices.

 LV_{DD} requires low current for the HV506 logic section. V_{DD} requires high current for the output section . Typically these two pins are at the same potential. The same current and potential conditions apply to the LV_{SS} , logic, and V_{SS} , output pins. V_{Sub} must always be equal or greater than the most positive supply.

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Electrical Characteristics

(over recommended operating conditions of $V_{DD} = 12V$, $LV_{DD} = 12V$, and $T_A = 25^{\circ}C$ unless noted)

DC Characteristics

Symbol	Parameter		Min	Max	Units	Conditions
I _{DD}	V _{DD} supply current			10	mA	f _{CLK} = 3MHz
I _{DDQ}	Quiescent V _{DD} supply cu	rrent		100	μΑ	All $V_{IN} = V_{SS}$ or V_{DD}
V _{OH}	High-level output	HV _{OUT}	V _{DD} -10		V	I _O = -300mA
		Data out	10.8		V	I _O = -100μA
V _{OL}	Low-level output	HV _{OUT}		V _{SS} +10	V	I _O = 300mA
		Data out		1.2	V	I _O = 100μA
I _{IH}	High-level logic input curr	rent		1	μΑ	$V_{IH} = V_{DD}$
I _{IL}	Low-level logic input curre	ent		-1	μΑ	$V_{IL} = V_{SS}$
I _{OFF}	Output OFF leakage curr	ent (High-Z)		10	μΑ	$ \begin{array}{l} HV_{OUT} \text{ - } V_{SS} = 275V, \\ V_{sub} = HV_{OUT} \end{array} $
				10	μΑ	V_{DD} - HV _{OUT} = 275V, V_{sub} = V_{DD}

Notes:

1. Only one output can be turned on at a time.

SCR Characteristics

Symbol	Parameter	Min	Max	Units	Conditions
V _{OH}	High-level output	V _{DD} -10		V	I _O = -300mA
V _{OL}	Low-level output		V _{SS} +10	V	I _O = 300mA
IL I	Latching Current		15	mA	
VL	Latching Voltage		100	V	
I _H	Holding Current	10		mA	
V _H	Holding Voltage	10		V	
I _{OFF}	Output OFF leakage current (High-Z)		10	μΑ	$\begin{array}{l} HV_{OUT} \text{-} V_{SS} = 275V, \\ V_{sub} = HV_{OUT} \end{array}$
			10	μΑ	V_{DD} - HV_{OUT} = 275V, V_{sub} = V_{DD}

AC Characteristics

Symbol	Parameter	Min	Max	Units	Conditions
f _{CLK}	Clock frequency		3	MHz	
t _{W (H/L)}	Pulse width - clock high or low	150		ns	
t _{SUD}	Data set-up time before clock rises	50		ns	
t _{HD}	Data hold time after clock rises	50		ns	
t _{SUC}	HV _{OUT} delay from clock rises (Hi-Z to H or L)		1	μs	$C_L = 10nF$
t _{SUE}	HV _{OUT} delay from Output Enable rises		600	ns	$C_L = 10nF$
t _{HC}	HV _{OUT} delay from clock rises (H or L to Hi-Z)		2	μs	C _L = 10nF
t _{HE}	HV _{OUT} delay from Output Enable rises		600	ns	$C_L = 10nF$
t _{DHL} *	Delay time clock to data output falls		250	ns	C _L = 15pF
t _{DLH} *	Delay time clock to data output rises		250	ns	C _L = 15pF
$t_{OFF(SCR)}$	Turn off time of output SCR		4	μs	Time after $I_{OUT} \le 2mA$, $C_L = 10nF$
t _{OFF(D)}	Turn off time of output diode		2	μs	Time after $I_{OUT} \le 2mA$, $C_L = 10nF$
t _{POW}	POL pulse width	3		μs	
t _{OEW}	Output Enable pulse width	3		μs	
SR	Slew rate of HV _{OUT}		200	V/µs	

* The delay is measured from the trailing edge of the clock but the data is triggered by the rising edge of the clock. There is an internal delay for the data output which is equal to t_{wh}. Therefore the delay is measured from the trailing edge of the clock.

Recommended Operating Conditions

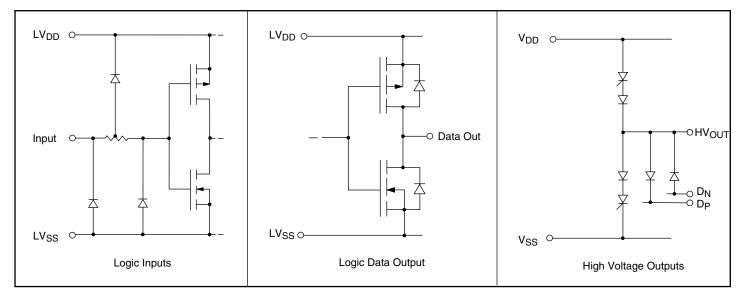
Symbol	Parameter	Min	Max	Units	
LV _{DD}	Logic supply voltage	10.8	13.2	V	
V _{DD}	Output supply voltage		10.8	13.2	V
V _{IH}	High-level input voltage	High-level input voltage		LV _{DD}	V
V _{IL}	Low-level input voltage		0	0.2LV _{DD}	V
f _{CLK}	Clock frequency	Clock frequency		3	MHz
Ι _Ο	High voltage output current	High voltage output current		±300	mA
T _A	Operating free-air temperature	Plastic	-40	+85	°C
	Ceramic		-55	+125	°C
I _{OD}	Allowable pulse current through diodes			±500	mA

Notes:

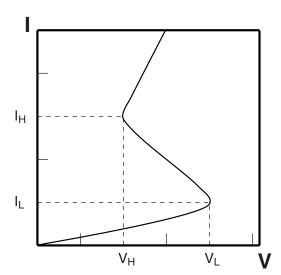
The substrate pin V_{sub} (pin 39) must be biased for proper output breakdown voltage. $V_{sub} \ge V_{DD}$ or HV_{OUT} whichever is higher.

 $\rm LV_{DD}/\rm V_{DD}$ are measured with respect to $\rm LV_{SS}/\rm V_{SS}.$

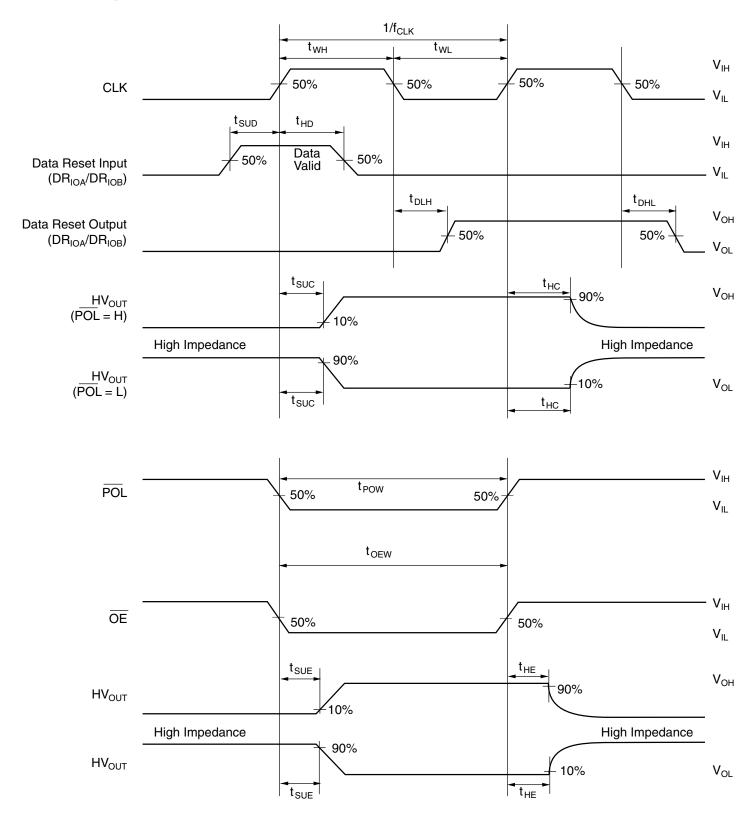
Input and Output Equivalent Circuits



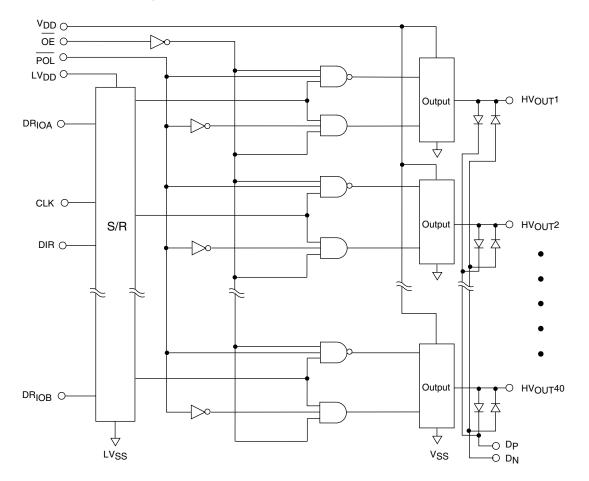
SCR Characteristics



Switching Waveforms



Functional Block Diagram



Function Table

I/O Relations	Inputs					
1/O Helations	CLK	DIR	S/R Data	POL	ŌĒ	HV Outputs
O/P HIGH	Х	Х	Н	Н	L	Н
O/P OFF	Х	Х	L	Х	L	HIGH-Z
O/P LOW	Х	х	Н	L	L	L
O/P OFF	Х	Х	Х	Х	Н	All O/P HIGH-Z

Note:

H = logic high level, L = logic low level, X = irrelevant

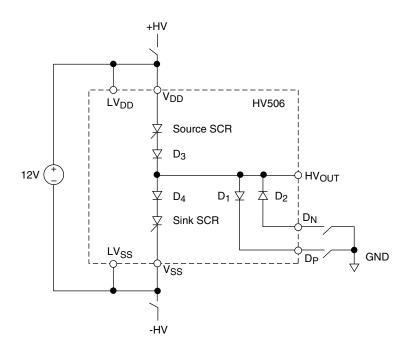
Output Sequence Operation Table

DIR	Data Reset In	Data Reset Out	HV _{OUT} # Sequence	Direction ³
L	DR _{IOB}	DR _{IOA} 1	40 → 1	
Н	DR _{IOA}	DR _{IOB} ²	1 → 40	$\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{\mathbf{$

Notes:

1. DR_{IOA} is DR_{IOB} delayed by 40 clock pulses. 2. DR_{IOB} is DR_{IOA} delayed by 40 clock pulses. 3. Reference to chip layout drawing.

Typical Output Circuit Connections

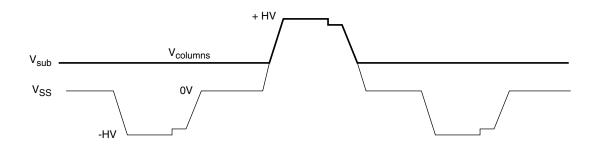


Note: The voltage potential between $\text{LV}_{\text{DD}}/\text{V}_{\text{DD}}$ and $\text{LV}_{\text{SS}}/\text{V}_{\text{SS}}$ must not exceed recommended operating conditions of 10.8V - 13.2V (12V typical)

Substrate Bias Operation

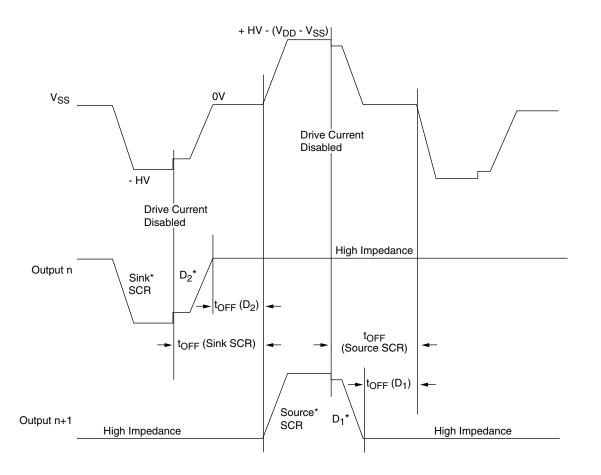
In order to achieve the desired output breakdown voltage, the substrate must be biased to the most positive potential of any circuit node. For this condition, $V_{sub} \ge V_{DD}$ or HV_{OUT} whichever is

higher. Refer to Typical Output Circuit Connections for wiring. A typical $\rm V_{sub}$ signal is shown below.



Note: In general, when driving the outputs positive, $V_{SUB} = +HV$. And when driving outputs negative, V_{SUB} equals most positive voltage; e.g. GND or >0V.

then discharged through a discharge diode when D_2 is switched to GND. The application of a positive pulse to a row operates in a similar manner using the selected source SCR and D_1 .



* Notes internal device handling current flow. Refer to Typical Output Circuit Connections for schematic.

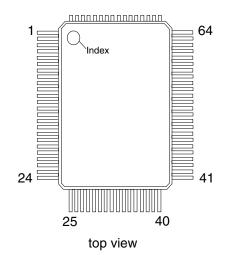
Pin Configurations

HV506

Onti	Option A:					
Pin	Function	Pin	Function			
1	HV _{out} 1	33	OE			
2	HV _{OUT} 2	34	POL			
3	HV _{out} 3	35	LV _{DD}			
4	HV _{OUT} 4	36	V _{ss}			
5	HV _{OUT} 5	37	V _{DD}			
6	HV _{OUT} 6	38	L V			
7	HV _{OUT} 7	39	V _{sub}			
8	HV _{OUT} 8	40	N/C			
9	HV _{OUT} 9	41	N/C			
10	HV _{OUT} 10	42	D _N			
11	HV _{out} 11	43	D _P			
12	HV _{OUT} 12	44	N/C			
13	ΗV _{ουτ} 13	45	HV _{OUT} 21			
14	HV _{OUT} 14	46	HV _{OUT} 22			
15	HV _{OUT} 15	47	$HV_{OUT}^{}23$			
16	ΗV _{ουτ} 16	48	HV_{OUT} 24			
17	ΗV _{ουτ} 17	49	$HV_{OUT}^{}25$			
18	HV _{OUT} 18	50	$HV_{OUT}^{}26$			
19	HV _{OUT} 19	51	HV _{OUT} 27			
20	HV _{OUT} 20	52	HV _{OUT} 28			
21	N/C	53	HV _{OUT} 29			
22	D _P	54	HV _{OUT} 30			
23	D _N	55	HV _{OUT} 31			
24	N/C	56	HV _{OUT} 32			
25	N/C	57	HV _{OUT} 33			
26	LV _{ss}	58	HV _{OUT} 34			
27		59	HV _{OUT} 35			
28	DIR	60	HV _{OUT} 36			
29 20		61 62	HV _{OUT} 37			
30 31	CLOCK	62 63	HV _{OUT} 38			
31	DR _{IOA}	63 64	HV _{OUT} 39			
32	DRIOR	04	HV _{OUT} 40			

Note: Pins 65-80 are NC.

Package Outline



3-sided Plastic 64-pin Gullwing Package



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